



DMTH3004LPSQ

30V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI

Small Form Factor Thermally Efficient Package Enables Higher

100% Unclamped Inductive Switching - Ensures More Reliability

Rated to +175°C – Ideal for High Ambient Temperature

Lead-Free Finish; RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) Qualified to AEC-Q101 Standards for High Reliability

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
	3.8mΩ @ V <sub>GS</sub> = 10V	145A
30V	6mΩ @ V <sub>GS</sub> = 4.5V	115A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- **Power Management Functions**
- **DC-DC Converters**

POWERDI<sup>®</sup>5060-8



- **Mechanical Data** 
  - Case: POWERDI<sup>®</sup>5060-8 •

**PPAP Capable (Note 4)** 

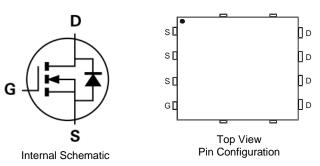
**Features and Benefits** 

**Density End Products** 

Environments

Low R<sub>DS(ON)</sub> – Minimizes On-State Losses Excellent Q<sub>qd</sub> x R<sub>DS(ON)</sub> Product (FOM)

- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



# Ordering Information (Note 5)

	Part Number	Case	Packaging		
DMTH3004LPSQ-13		POWERDI <sup>®</sup> 5060-8	2,500/Tape & Reel		
Notes:	1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.				

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

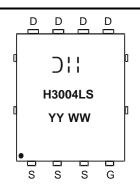
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# Marking Information



) | | = Manufacturer's Marking H3004LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 15 = 2015)WW = Week (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	30	V
Gate-Source Voltage		V <sub>GSS</sub>	+20 -16	V
Continuous Drain Current (Note 6)	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	Ι <sub>D</sub>	22 16	А
Continuous Drain Current (Note 7)	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	Ι <sub>D</sub>	145 103	A
Maximum Continuous Body Diode Forward Current		ls	100	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	180	А
Avalanche Current, L=0.3mH		I <sub>AS</sub>	27	А
Avalanche Energy, L=0.3mH		E <sub>AS</sub>	110	mJ

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation	PD	136	W	
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0JA</sub>	47	80 M	
Thermal Resistance, Junction to Case (Note 7)	R <sub>ejc</sub>	1.1	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C	

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Cymbol		אני	max	Unit		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_		V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μA	$V_{DS} = 24V$ , $V_{GS} = 0V$	
Zero Gate Voltage Drain Current (Note 9)	IDSS	_	_	10	μA	$V_{DS} = 24V, V_{GS} = 0V$ T <sub>J</sub> = +125°C	
Gate-Source Leakage	I <sub>GSS</sub>	_		±100	nA	$V_{GS} = +20V, V_{DS} = 0V$ $V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)						-	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	1.6	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Proven		3.3	3.8	mΩ	$V_{GS} = 10V, I_D = 20A$	
	R <sub>DS(ON)</sub>	_	5	6	11122	$V_{GS} = 4.5V, I_D = 7A$	
Diode Forward Voltage	V <sub>SD</sub>	—	0.70	1	V	$V_{GS} = 0V$ , $I_S = 1A$	
DYNAMIC CHARACTERISTICS							
Input Capacitance (Note 9)	Ciss	—	2370	—		V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1MHz	
Output Capacitance (Note 9)	Coss	—	1360	—	pF		
Reverse Transfer Capacitance (Note 9)	C <sub>rss</sub>	_	240	—			
Gate Resistance	Rg	0.14	0.7	1.75	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
SWITCHING CHARACTERISTICS (Note 9)							
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	—	43.7	—			
Gate-Source Charge	Q <sub>gs</sub>	—	6.9	—	nC	$V_{DS} = 15V, I_D = 20A$	
Gate-Drain Charge	Q <sub>gd</sub>	-	8	—			
Turn-On Delay Time	t <sub>D(ON)</sub>	—	6.2	—		$V_{DD} = 15V, V_{GS} = 10V,$ $R_G = 3\Omega, R_L = 0.75\Omega$	
Turn-On Rise Time	t <sub>R</sub>	-	4.2	—			
Turn-Off Delay Time	tD(OFF)	_	21	—	ns		
Turn-Off Fall Time	t <sub>F</sub>		8	_			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	—	25	—	ns		
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	37	_	nC	nC $I_F = 15A$ , dI/dt = 500A/µs	

Notes: 6. Device mounted with exposed drain pad on 25mm by 25mm 2oz copper on a single- sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady state.

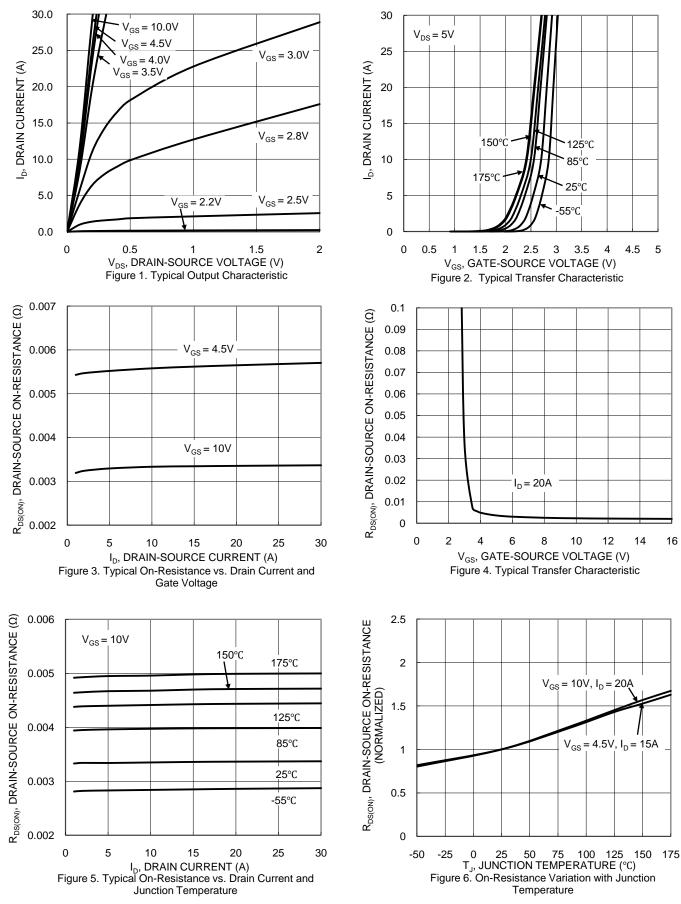
7. Thermal resistance from junction to soldering point (on the exposed drain pad).

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to production testing.



#### DMTH3004LPSQ

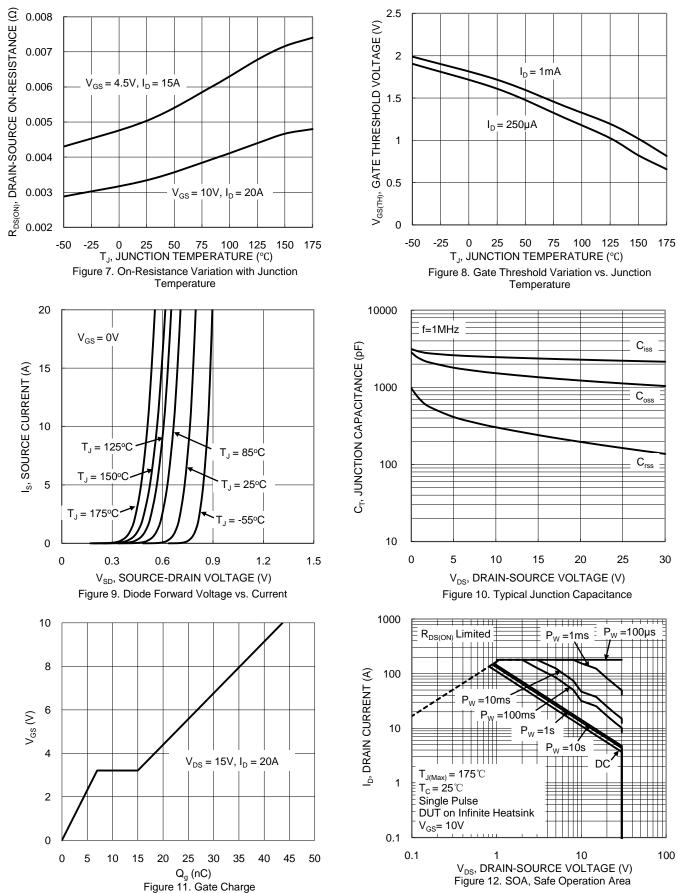


PowerDI is a registered trademark of Diodes Incorporated. DMTH3004LPSQ Document number: DS38443 Rev. 1 - 2

3 of 7 www.diodes.com



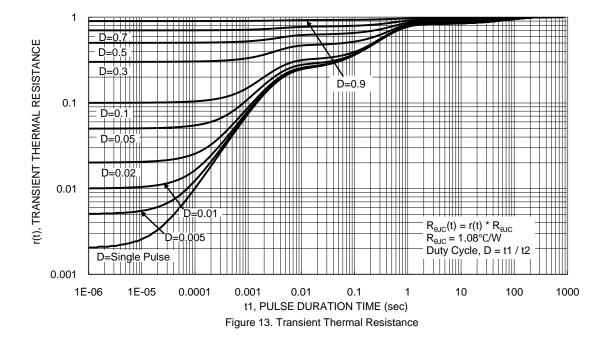
## DMTH3004LPSQ



PowerDI is a registered trademark of Diodes Incorporated. DMTH3004LPSQ Document number: DS38443 Rev. 1 - 2

4 of 7 www.diodes.com

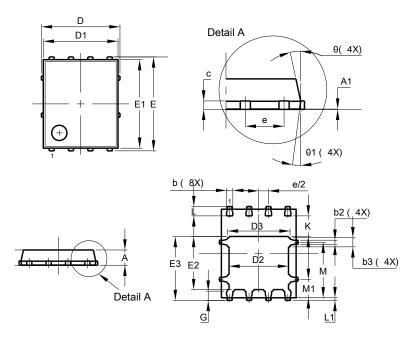






# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



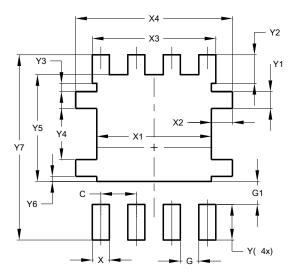
POWERDI <sup>®</sup> 5060-8					
Dim	Min	Тур			
A	0.90	Max 1.10	1.00		
A1	0.00	0.05	_		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	ļ	5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	(	6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10º	12º	11º		
Θ1	6º	8º	7°		
All Dimensions in mm					

### POWERDI<sup>®</sup>5060-8

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### POWERDI<sup>®</sup>5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

PowerDI is a registered trademark of Diodes Incorporated. DMTH3004LPSQ Document number: DS38443 Rev. 1 - 2



#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by Diodes Incorporated manufacturer:

Other Similar products are found below :

614233C 648584F MCH3443-TL-E MCH6422-TL-E FDPF9N50NZ FW216A-TL-2W FW231A-TL-E APT5010JVR NTNS3A92PZT5G IRF100S201 JANTX2N5237 2SK2464-TL-E 2SK3818-DL-E FCA20N60\_F109 FDZ595PZ STD6600NT4G FSS804-TL-E 2SJ277-DL-E 2SK1691-DL-E 2SK2545(Q,T) D2294UK 405094E 423220D MCH6646-TL-E TPCC8103,L1Q(CM 367-8430-0972-503 VN1206L 424134F 026935X 051075F SBVS138LT1G 614234A 715780A NTNS3166NZT5G 751625C 873612G IRF7380TRHR IPS70R2K0CEAKMA1 RJK60S3DPP-E0#T2 RJK60S5DPK-M0#T0 APT5010JVFR APT12031JFLL APT12040JVR DMN3404LQ-7 NTE6400 JANTX2N6796U JANTX2N6784U JANTXV2N5416U4 SQM110N05-06L-GE3 SIHF35N60E-GE3